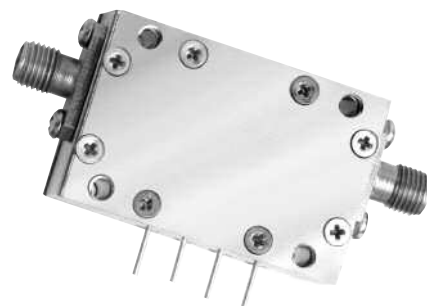


2 TO 18 GHz TTL BIPHASE MODULATOR

MODEL: BMT0218HC10MD (Modulation Driven)

FEATURES

- RF frequency range..... 2 to 18 GHz
- Biphase accuracy $\pm 5^\circ$
- Amplitude accuracy ± 0.5 dB
- Rise time 10 ns
- Switching speed 30 ns
- RF input..... +15 dBm (P1 dB)

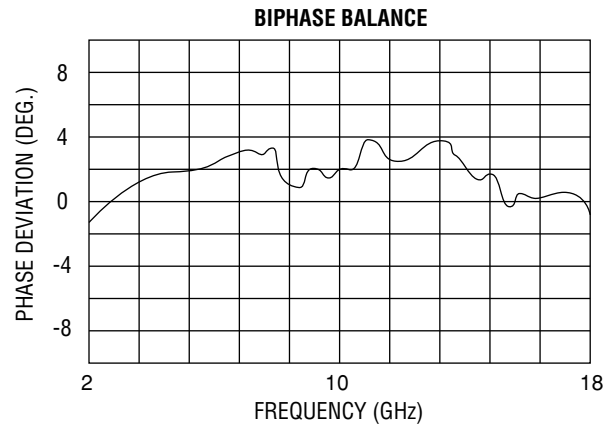
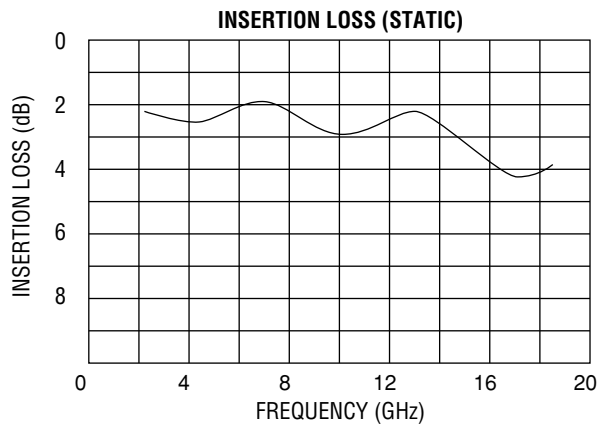
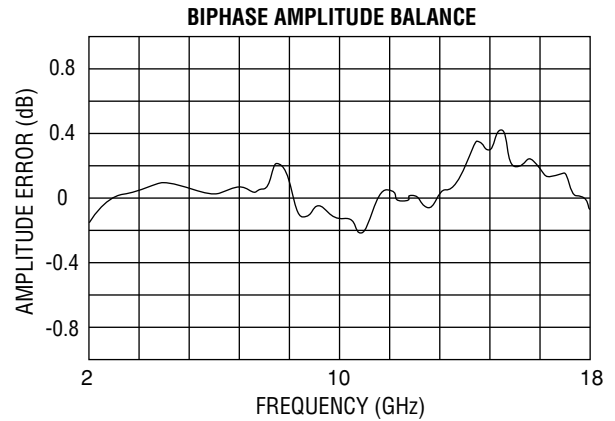
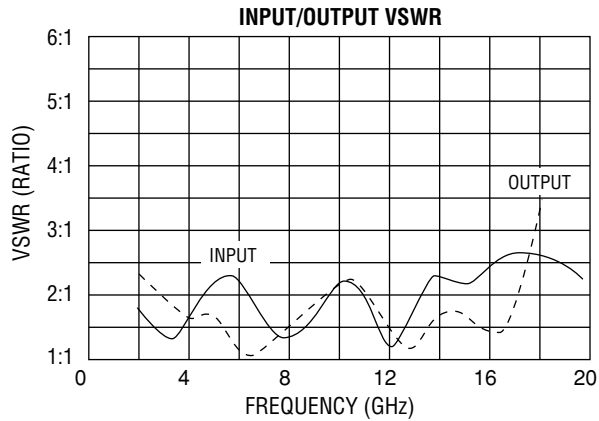


MITEQ's Model BMT0218HC10MD TTL-controlled biphase modulator is ideal for BPSK modulation over broad frequency ranges with extremely high input carrier levels (up to +20 dBm). The power handling capability is suited to simulator systems using high-level VCOs avoiding the requirement of an additional external amplifier. Since this is a TTL or modulation driven unit, the RF input-to-output power relation is linear up to the compression level.

ELECTRICAL SPECIFICATIONS

INPUT PARAMETERS	CONDITION	UNITS	MIN.	TYP.	MAX.
RF carrier frequency range		GHz	2		18
RF carrier VSWR		Ratio		2.8:1	3.5:1
RF carrier power (linear)	Operating Nonoperating	dBm dBm	+15	+20 +23	
TTL modulation rate		MHz	DC		30
DC power supply	± 5 VDC	mA			30
TRANSFER CHARACTERISTICS	CONDITION	UNITS	MIN.	TYP.	MAX.
Insertion loss		dB		4.	6
Carrier suppression		dBc	20	25	
Switching speed	50% TTL to 90% RF	ns		30	
Switching rise/fall time	10 to 90% RF	ns		10	
Phase balance (0 or 180°)		Degrees		± 5	± 10
Amplitude balance (0 or 180°)		dB		± 0.5	± 0.75
OUTPUT PARAMETERS	CONDITION	UNITS	MIN.	TYP.	MAX.
Modulated RF frequency range		GHz	2		18
Modulated RF VSWR		Ratio		2.8:1	3.5:1
Video leakage	From 2 to 18 GHz	dBm		-65	

BMT0218HC10MD MODULATION DRIVEN TYPICAL TEST DATA

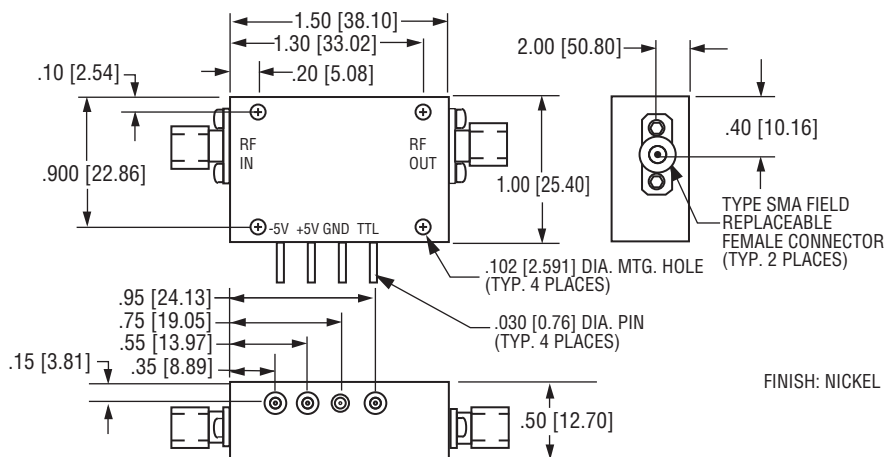


MAXIMUM RATINGS

Specification temperature	+25°C
Operating temperature	-54 to +85°C
Storage temperature	-65 to +125°C
Weight	26 grams

NOTE: Test data supplied at 25°C; insertion loss and biphas accuracy.

OUTLINE DRAWING



NOTE: All dimensions shown in brackets [] are in millimeters.